

SiTRA report

EUDET S.C. August 27, 2007



Status of deliverables:

- Large size prototypes
 - Cooling prototype
 - Alignment prototype
 - Front end electronics
 - Test beams
- Appointments and Finances

Aurore Savoy-Navarro, LPNHE-UPMC/CNRS-IN2P3

On behalf of the SiTRA activity in EUDET:

*HIP-Helsinki, LPNHE-Paris, Charles U. Prague, IFCA/CSIC Santander
and*

*IMB-CNM/CSIC Barcelona, IEKP-Karlsruhe, Liverpool University,
OSU Obninsk, IFIC/CSIC-Valencia, HEPHY Vienna
(associated Institutes)*

The work reported here is also part of the SiLC R&D Collaboration

1°) Construction of large structure Silicon tracking prototypes for test beam

- New sensors
 - ▶ New μ strip sensors from HPK, including test structures and special treatment for alignment.
 - ▶ Thinning tests by LPNHE with Edgetek
 - ▶ Direct wiring of the FEE onto μ pistes (LPNHE, HPK)
 - ▶ Prospects: New Firms (apart from HPK), New technology
- Developing tooling for new module construction
 - ▶ Based on already existing one: IEKP
 - ▶ Starting expertise: LPNHE (plus collaboration with CERN)
- Design and construction of large prototypes
 - ▶ Two main cases:
 - plans of Si layers for central or XUV Forward (1st by end 2007)
(can be used for combined tests with μ vertex or calorimeter prototypes)
 - and prototype for LCTPC combined test (Fall 2008)

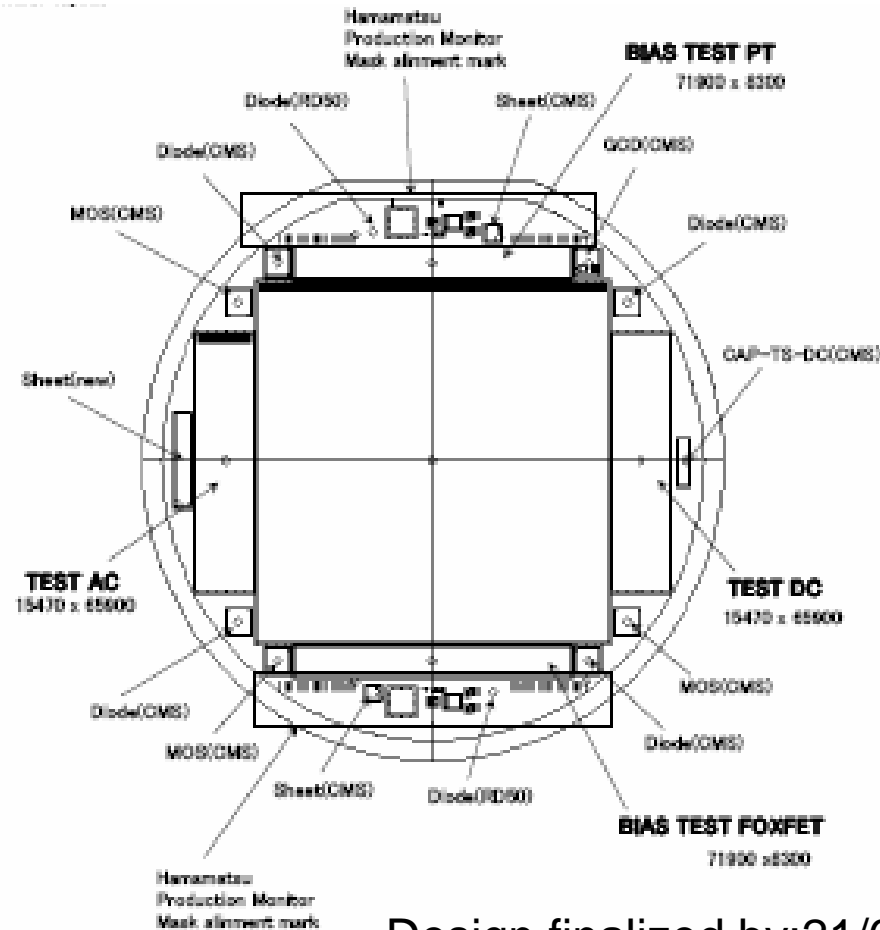
N.B. NO EU funds for construction of large size Si structures/prototypes

SilC work program for sensor R&D 2007-2008

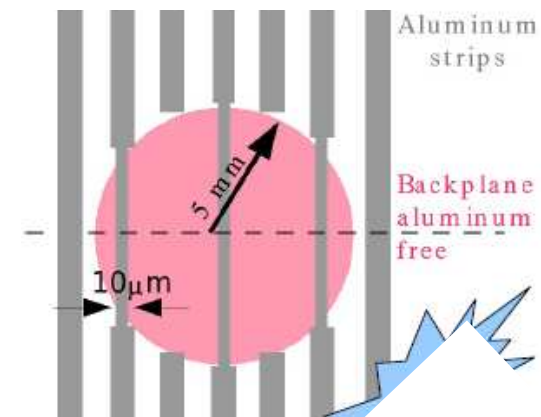
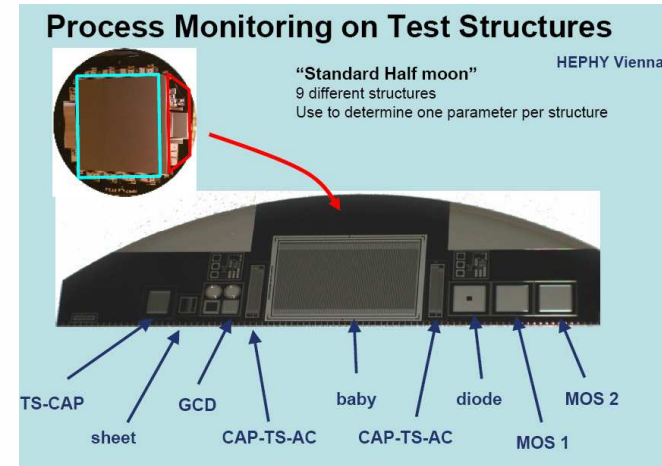
IEKP Karlsruhe, HEPHY Vienna, LPNHE, IFCA+IMB/CSIC, HPK

- Step 1 (2007)
 - ✓ Wafer thinning (100, 200, 300 μ m)
 - ✓ Strips larger wafer (50 μ m pitch)
 - Test new readout chips (DC coupling, power cycling)
 - ✓ Improve standardized test structures and test setups
- Step 2a (2008-)
 - ✓ Move from pitch adapter to in-sensor-routing
 - Test crosstalk, capacitive load of those sensors
- Step 2b (2008-)
 - ✓ Test 6" double sided sensors (LPNHE + Canberra)
- Step 2c (2008-)
 - 8" (12") single sided DC wafer
- Step 3 (2007-)
 - New firms (Liverpool+Micron & E2V)
 - New technology (IMB-CNM, HIP, VTT, HEPHY, LPNHE)

New 6" μ strip wafers (HPK), tests structure(HEPHY) under production: sensors are $9.05 \times 9.05 \text{cm}^2$, $320 \mu\text{m}$ thick, $50 \mu\text{m}$ pitch; 5 sensors out of 35 ordered are speciall treated for alignment with laser; Expected to be delivered by mid Sept so (hopefully) available for Oct 07 and for sure for LCTPC 08.



Design finalized by:21/6/07

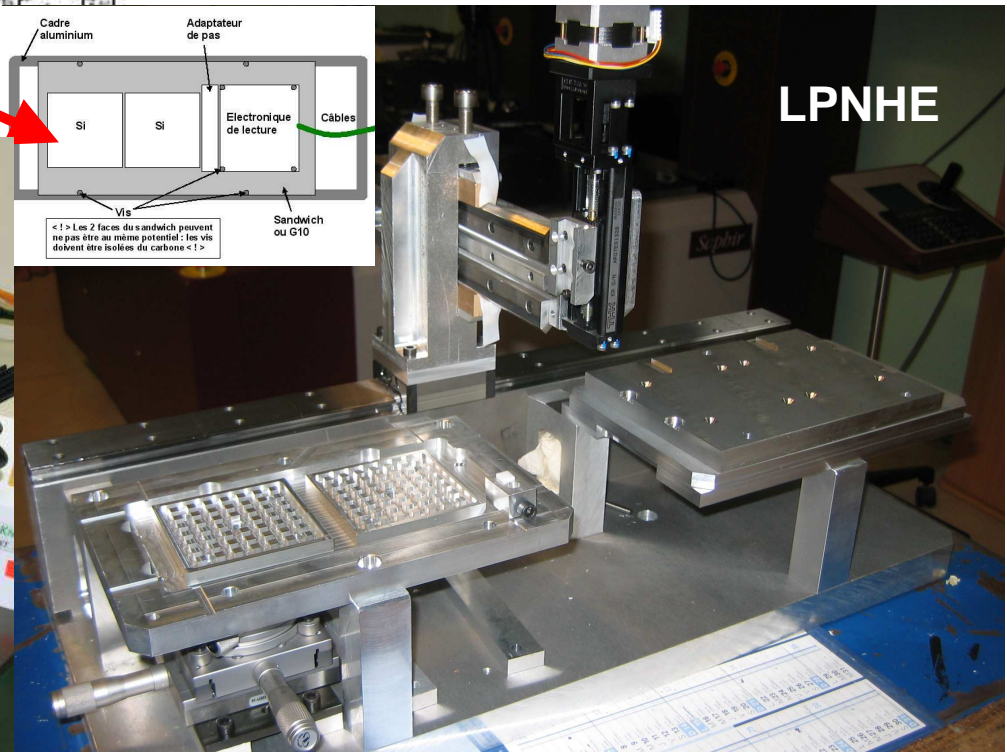
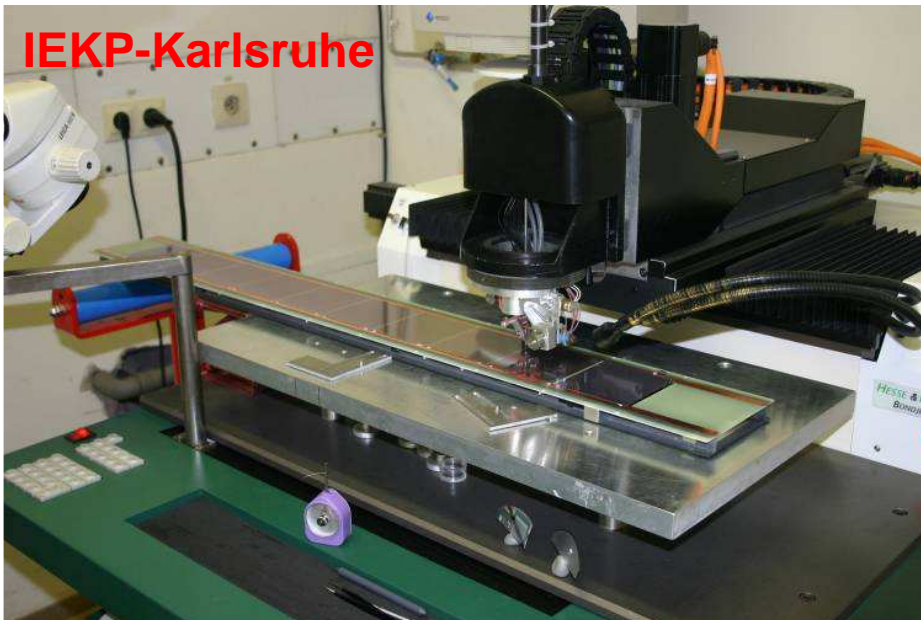
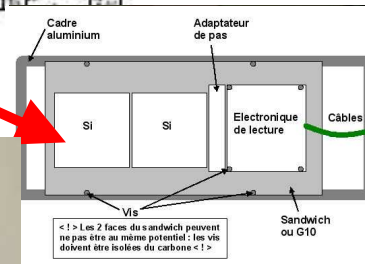
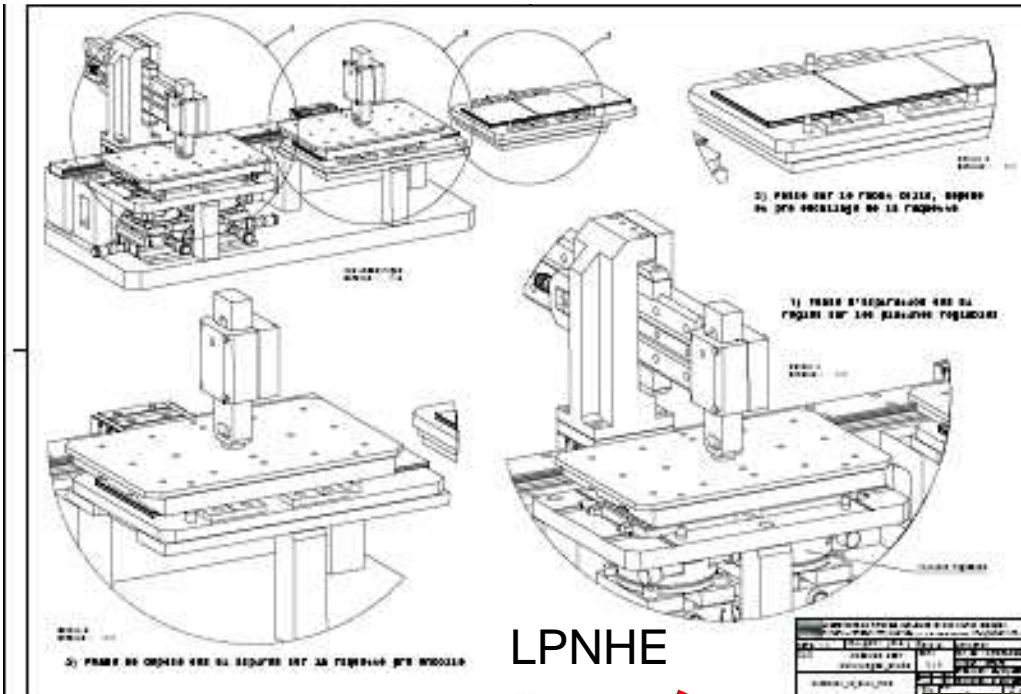


5 wafers treated for alignment

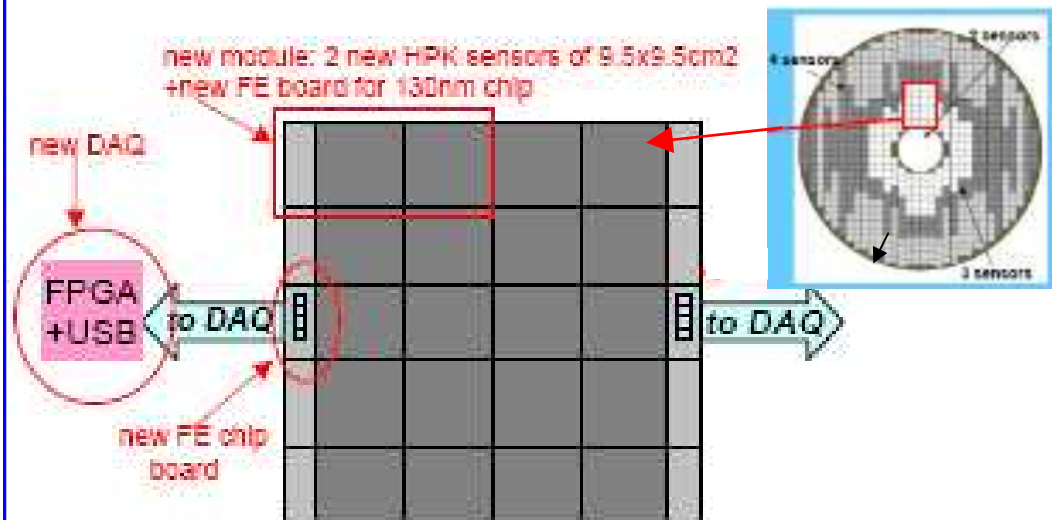
N.B.: NO E.U. funding for Si sensors

Tooling for construction of modules:

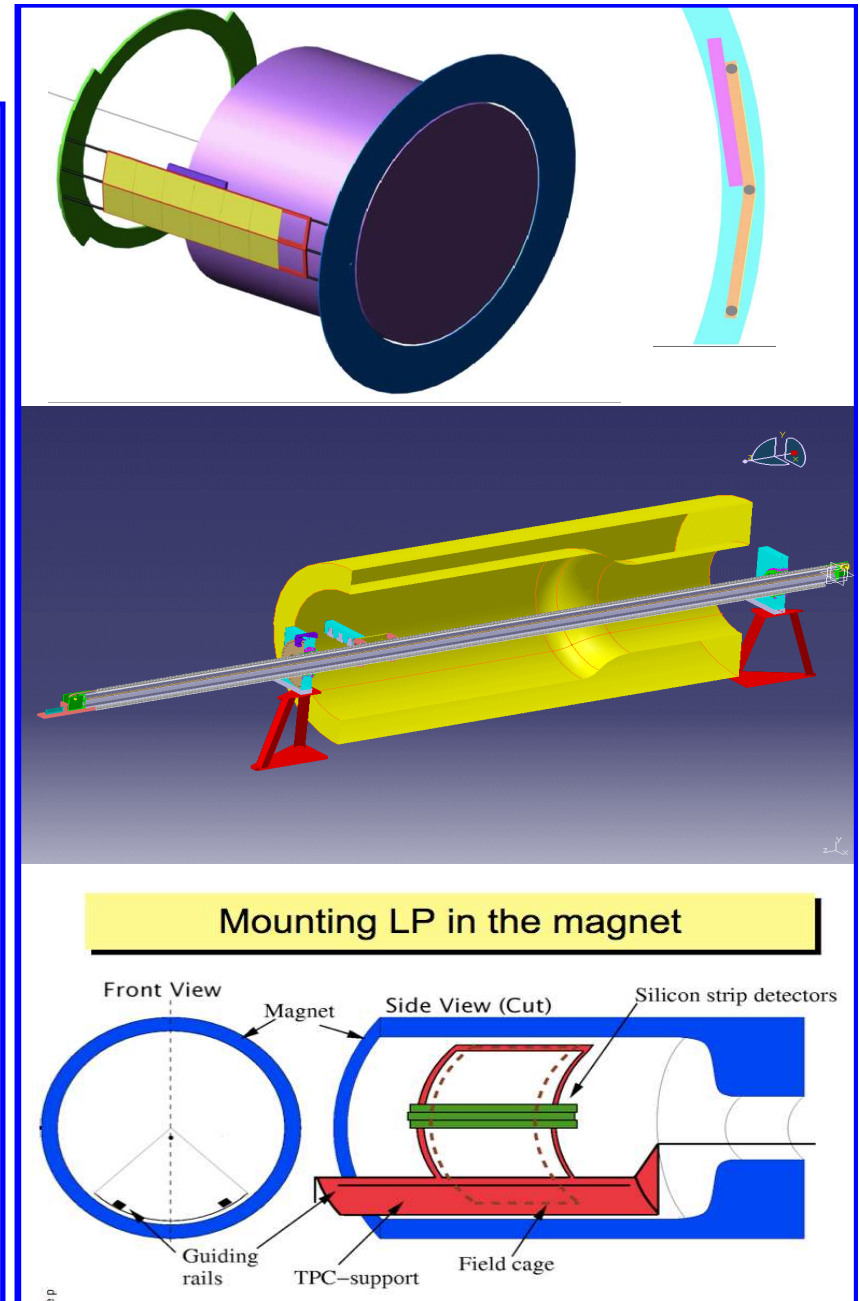
- Need for developing new expertise and tooling at LPNHE (well in progress)
- and use of already existing expertise and tooling: IEKP Karlsruhe
- Bonding Lab at CERN (A. Honma, I. McGill, M. Moll)



Large size Si prototypes:



- ✓ First prototype of large size (**mechanical structure ready end of 2007**). Evolutive system.
- ✓ 2 first modules will be tested in CERN T.B. in Oct 2007.
- ✓ Four such plans to be built and equipped (sensors and FEE) for 2008-2009 T.B.
- ✓ Will provide 2 XY/track or 1 XUV if FWD.
- ✓ Cooling prototype will be adapted to it.
- ✓ System available for combined test beam with μ vertex prototypes and/or Calorimeter prototypes
- ✓ Alignment system prototype (IFCA) will be included to it.



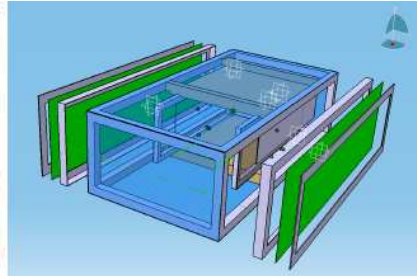
Tests with LCTPC (Fall 08)
IEKP, HEPHY, DESY, LPNHE

2°) COOLING PROTOTYPE (LPNHE + OSU + Torino U.)

Cooling and insulating frame (see presentation at EUDET S.B., 21/5/07)
prototype expected to be ready for October 2007

N.B. almost NO funding from E.U.

Insulating cage for DESY test beam



Final prototype in composite material will be made with help of OSU & Torino U.



Actual FEE results: $\sim 0.6 \text{mWatt/ch}$
 No Power cycling included yet
 → Main problem: power dissipation from neighbours

	Preamp	Shaper	Zero suppr	Pipe- line	Total Analog	ADC	Logic	Total Digital
180nm/ch	90	180			270			
130nm/ch	148	148	198	10	375	66		
Common				100		5	96	101

3°) Alignment prototype

Basic idea (developed first by AMS & CMS):

Use laser beam in the IR region (“pseudo-track” of infinite momentum) to cross several sensors consecutively. Main advantages:

- **No mechanical transfer errors between fiducial marks and the modules**
- **Minimum impact on system integration and none on DAQ**

Two-fold approach:

1) *Integration with SiTra:*

1.1) Mandatory change in the module:

∅~10 mm window where Al back-metalization has been removed (requires 1 new mask and sensor backprocessing)

(This is included in new HPK sensors)

1.2) Optional changes in alignment window

Strip width reduction
Alternate strip removal
Thickness
optimisation

Transmittance
improved

2) *R&D on transparent Silicon μ strip sensors:*

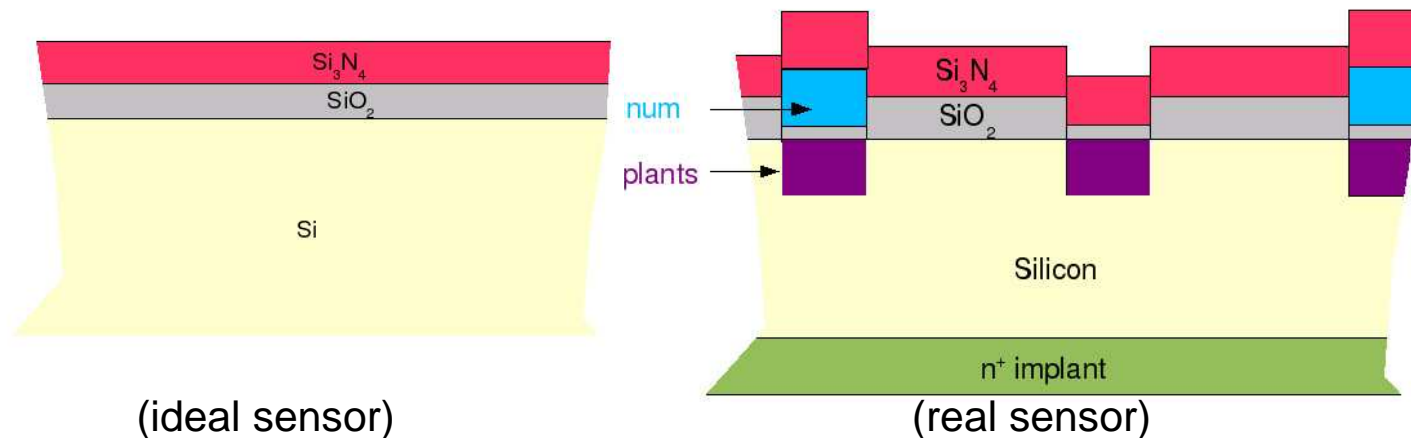
- IFCA with IMB-CNM (Barcelona) develops prototypes of new sensors that can achieve maximum transmittance in a wavelength range
- Aluminium electrodes and strip are perfect mirrors. Substitute Al electrodes by TRANSPARENT ELECTRODES (ITO, AZO....)
- Wide margin for changes and experimentation to obtain best optical and electrical sensor

SiTra prototype:

Ordered 5 sensors to HKP with alignment window (to be tested on optical test bench & test beam)

R&D IFCA-Santander&CNM-Barcelona:

- ❖ Scalar simulation of multiple reflections inside the multilayer of the sensor ... **done**
- ❖ Optimization of multilayer design to achieve maximum T at $\lambda_{IR} \pm 5\text{nm}$ (laser spectral width) ... **done**
- ❖ Vectorial simulation of diffraction processes due to strip segmentation ... **in progress**



Basic samples will be produced by IMB-CNM on September to:

- characterise each layer individually (refraction indexes)
- study the effect of Silicon doping on transmittance
- Validate scalar and vectorial simulation

Optical testbench

Lab testbench for sensor characterization commissioned at IFCA

Component status:

Focusing & steering optics already received

DAQ electronics available and currently under programming

Automated 3D stages by the end of September

Beta source for testing by the end of the year

Black-box under construction

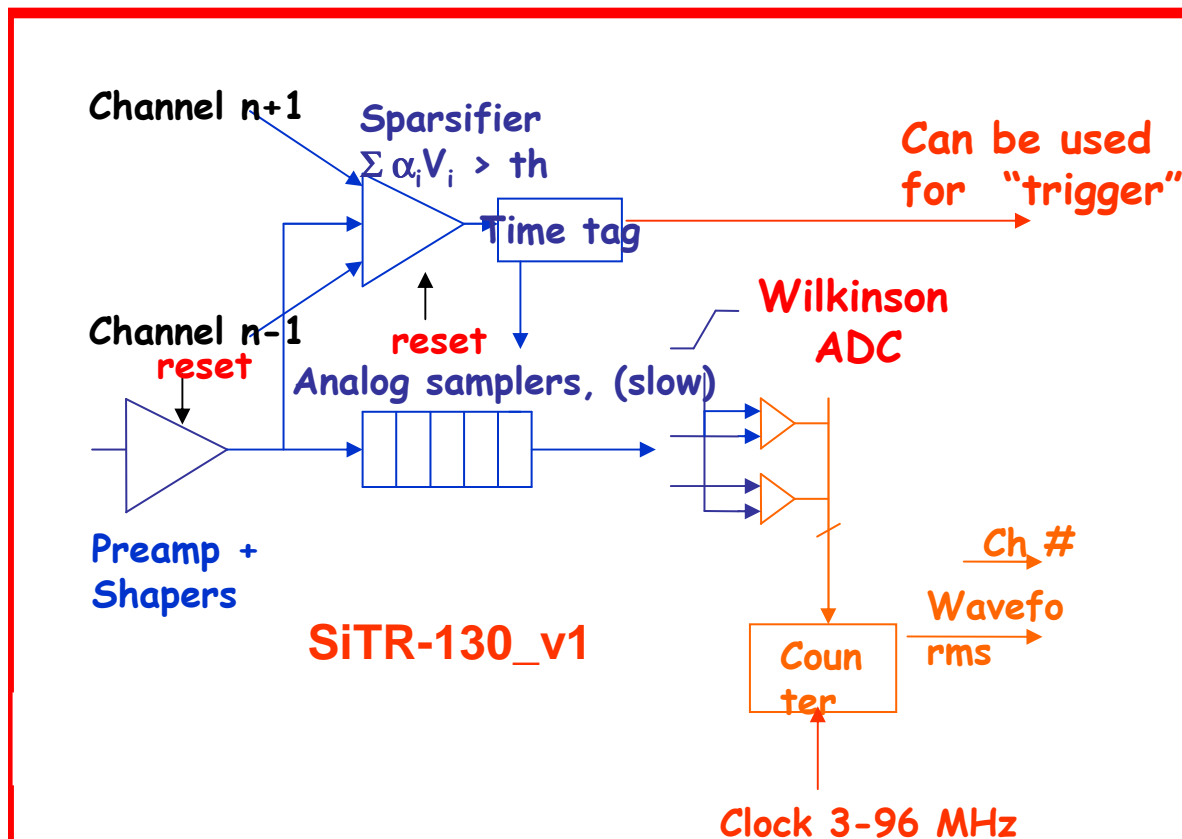
IR laser @ 1060 nm



N.B. NO Funding from E.U. except for F.E.E.

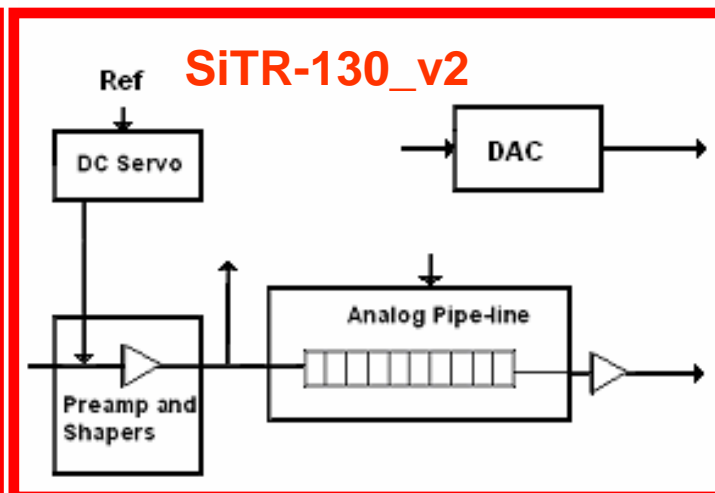
4°) FE Electronics: (LPNHE + LAPP (SiLC))

- Tests of 2 versions SiTR-130_v1 et _v2 sent in foundry in 2006
- Design of SiTR-130 for mini production and equipment of prototypes in 2008



Version 1: LPNHE Received end 2006

Tests in functionality OK, tests with Si detector & detailed characterisation: in progress

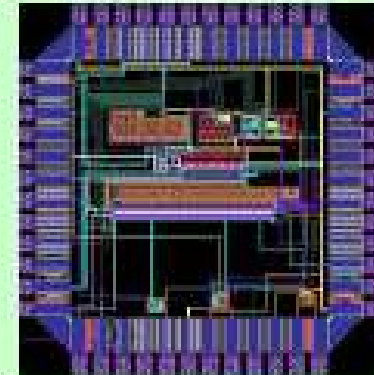


Version 2: LAPP

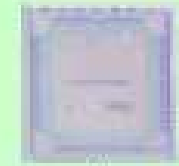
(D. Fougeron + R. Hermel)
 DC servo adapted to sensors with DC coupling
 DAC: calibration

Pipeline improved wrt version v1.
Received 5/1/07: test at LAPP

Layout & photographs of the chips SiTR-130_1 et _2

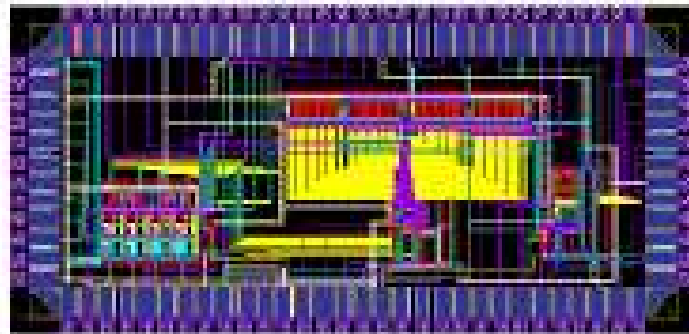


Layout

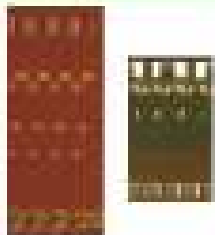


Picture

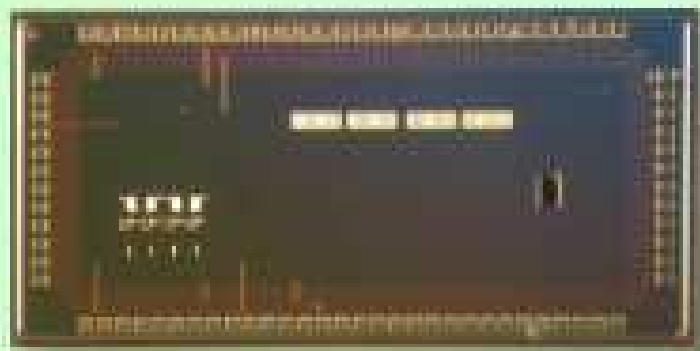
One channel 1.5 x 1.5 mm²



Layout of the 130nm chip including sampling and A/D conversion



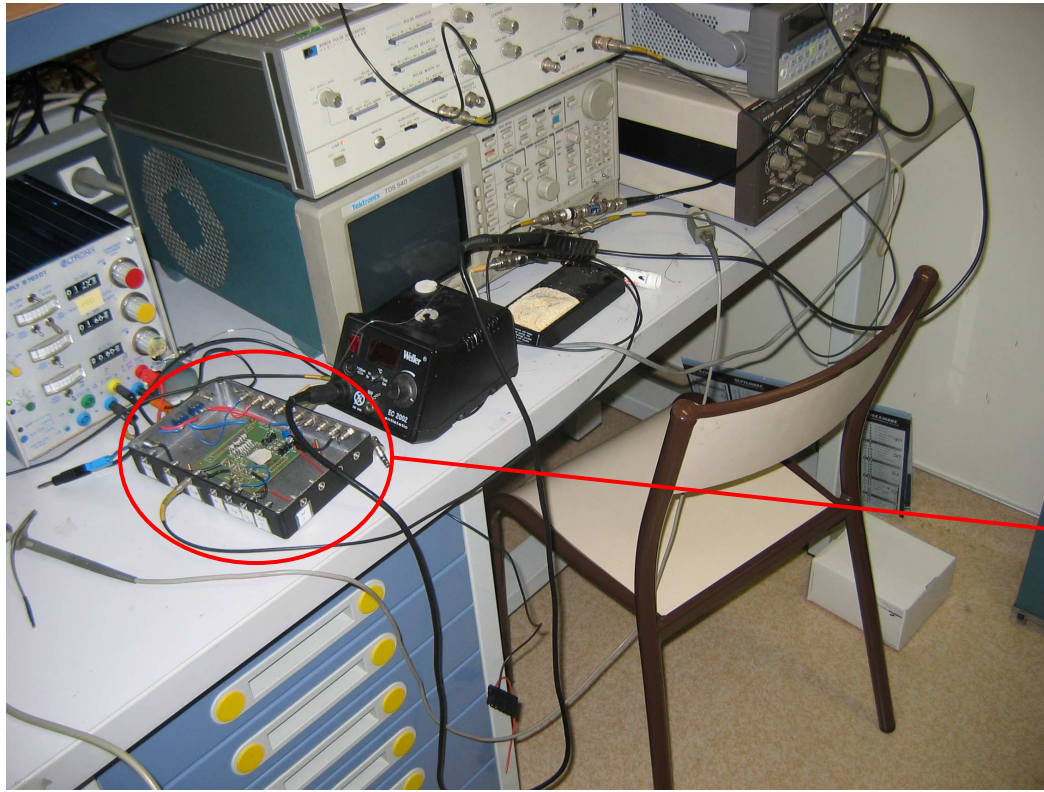
180nm 130nm



Picture

Chips received end 2006
and beginning 2007.
Both tested in 2007

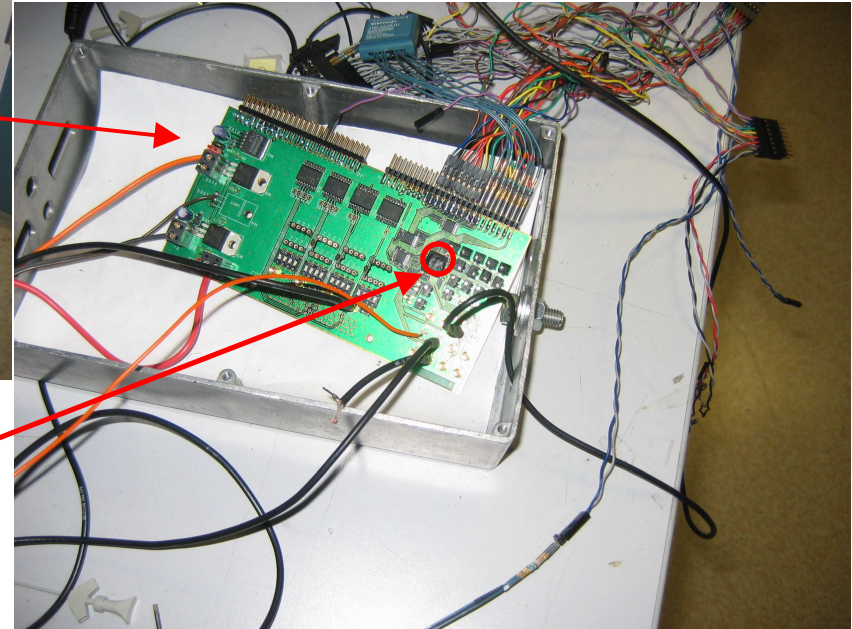
Functionality tests of SiTR-130_v1



Lab test bench of functionality of the chip
at LPNHE

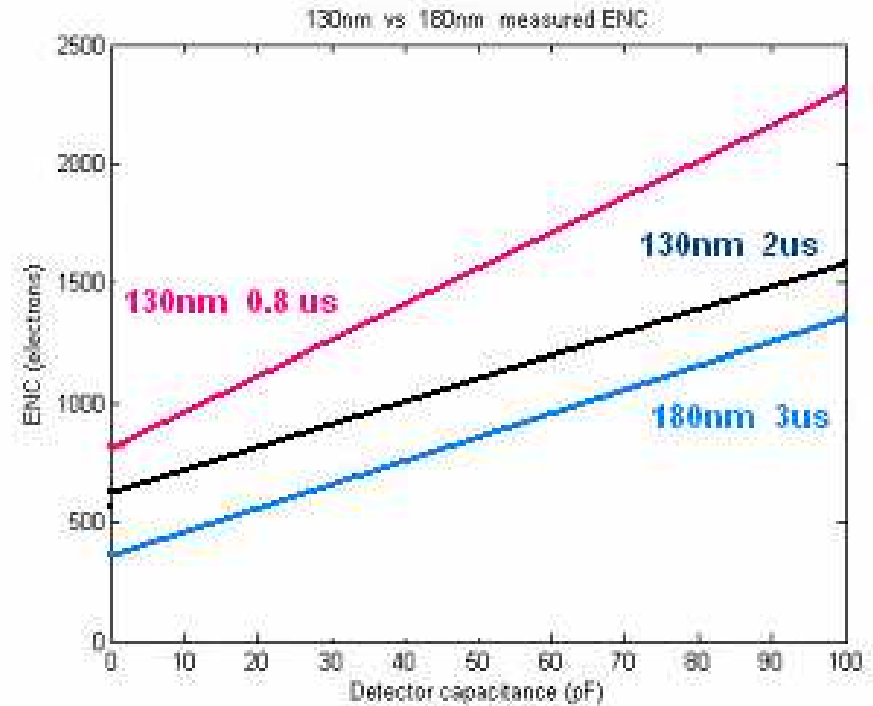
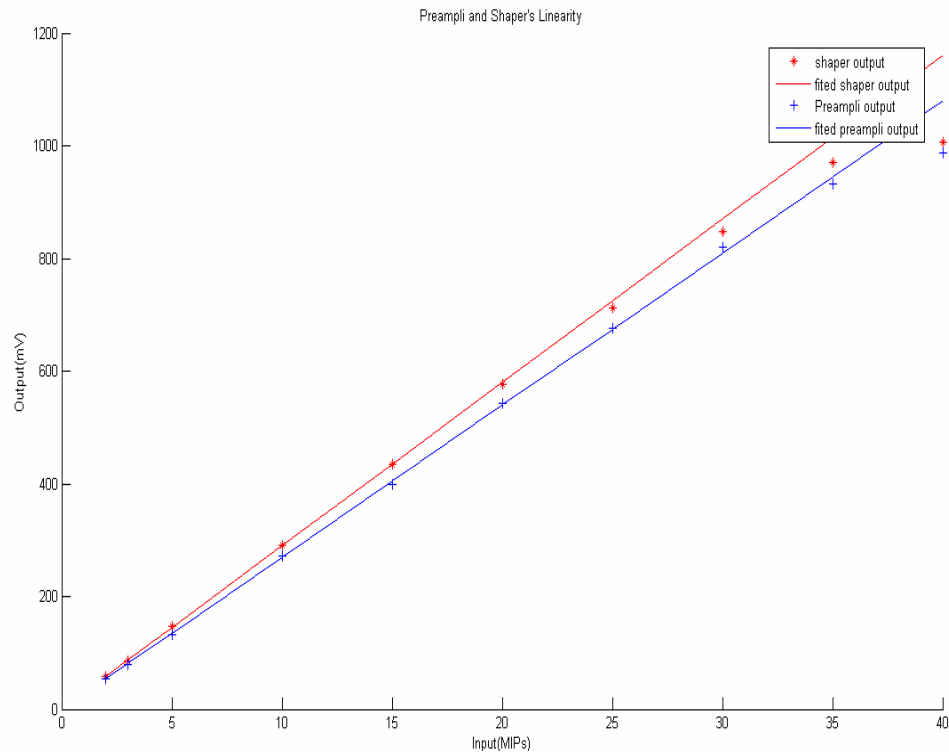
Chip SiTR-130_v1

Test board for SiTR-130_v1



Another test bench system is being installed at LAPP in order to fully test SiTR-130_v2 . This test bench will be fully automatized.

Results in functionality of SiTR-130 v1



Preamplificateur :

Gain = 27mV/MIP

Dynamique = 25MIPs (<1%)
= 30MIPs (<5%)

Shaper :

Gain = 29mV/MIP

Dynamique = 20MIPs (<1%)
= 30MIPs (<5%)

Performance en Bruit:

130nm @ 0.8 μs : 850 + 14 e-/pF

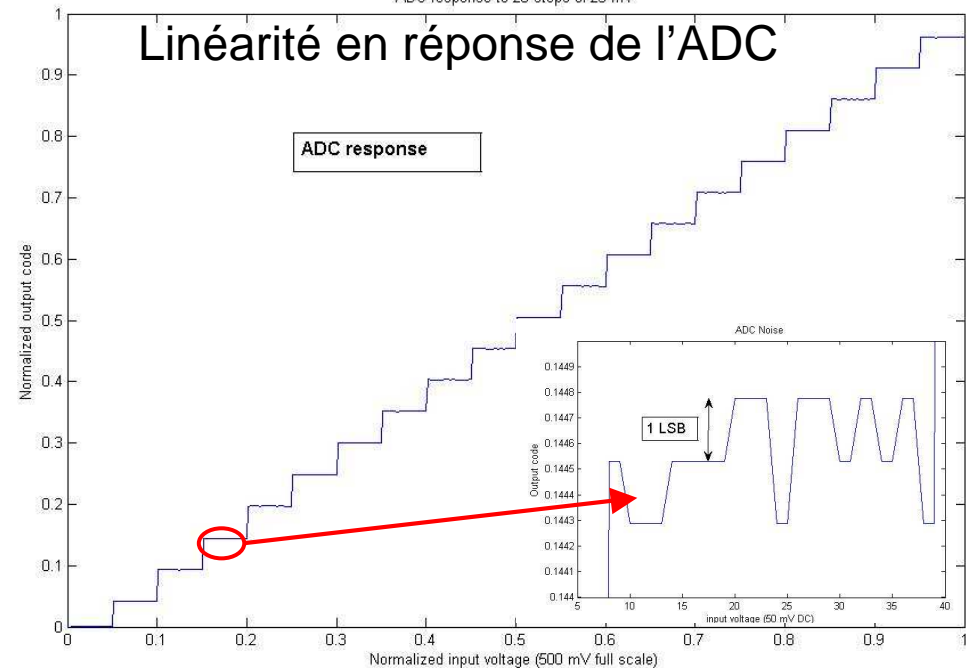
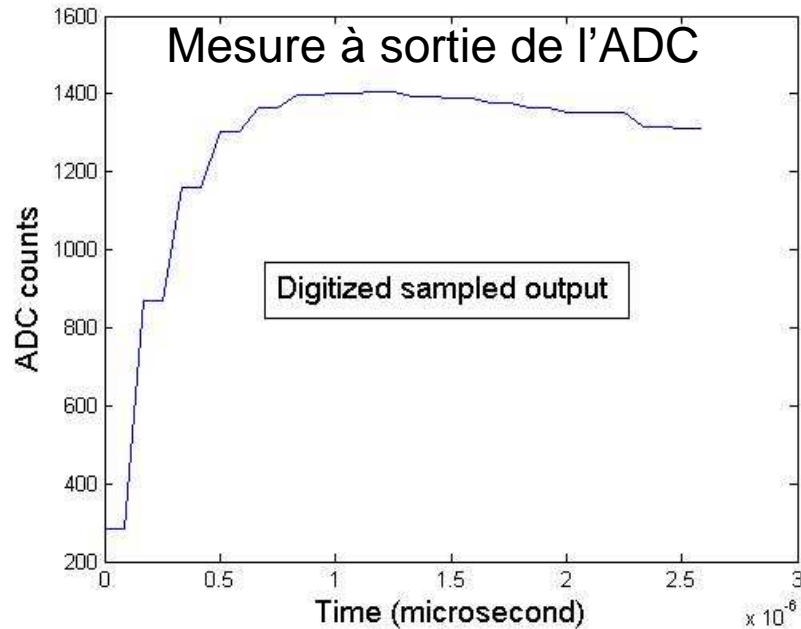
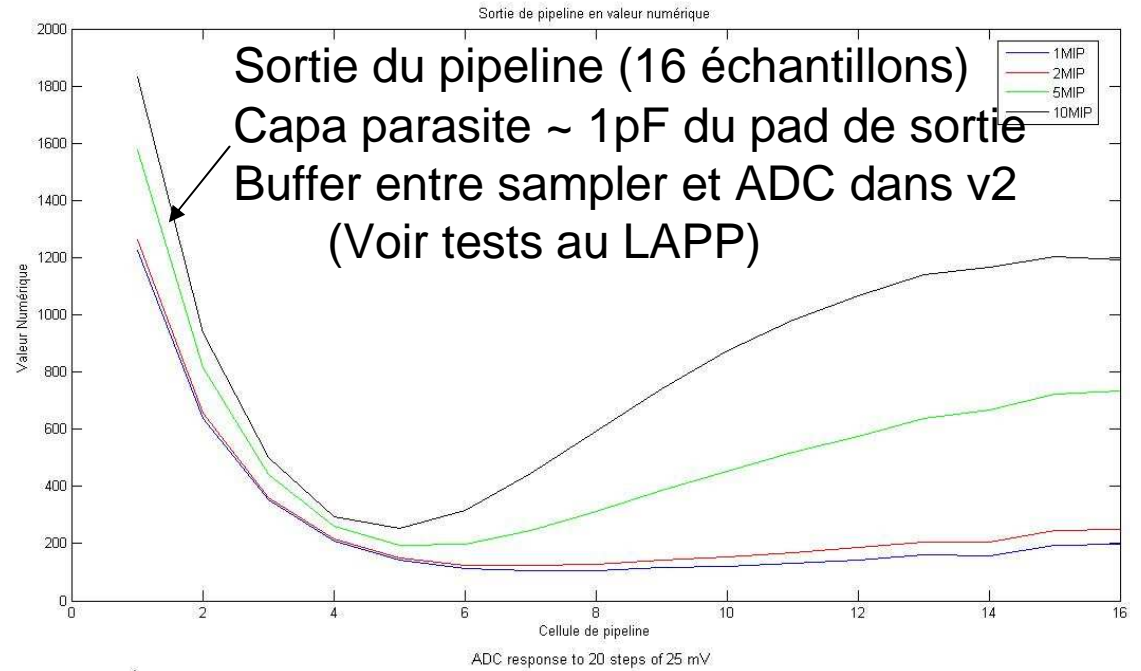
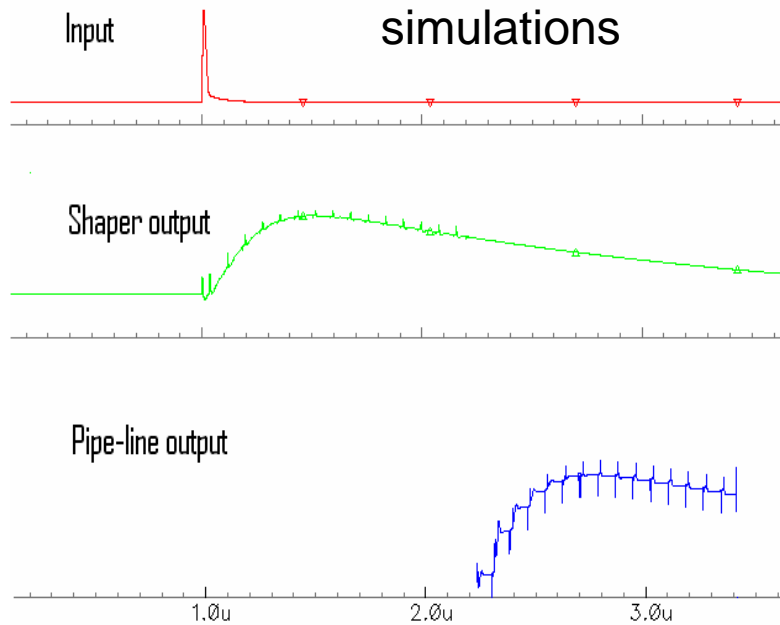
130nm @ 2 μs : 625 + 9 e-/pF

625*sqrt(2/3)=510 e-/pF

180nm @ 3 μs : 375 + 10.5 e-/pF

Puissance (Preamp+ Shaper) = 290 mW

Results in functionality of SiTR-130_v1 => OK

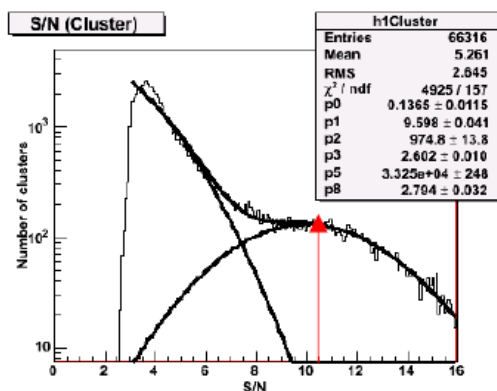


SiTR-130_v1 et v2: still to be done

Detailed characterisation of the A/D converter

- Linearities integral, differential
- Noise fixed pattern, random
- Speed Maximum clock frequency

*Number of effective bits (ENOB)
and full characterization of SiTR-130_v2 autLAPP*

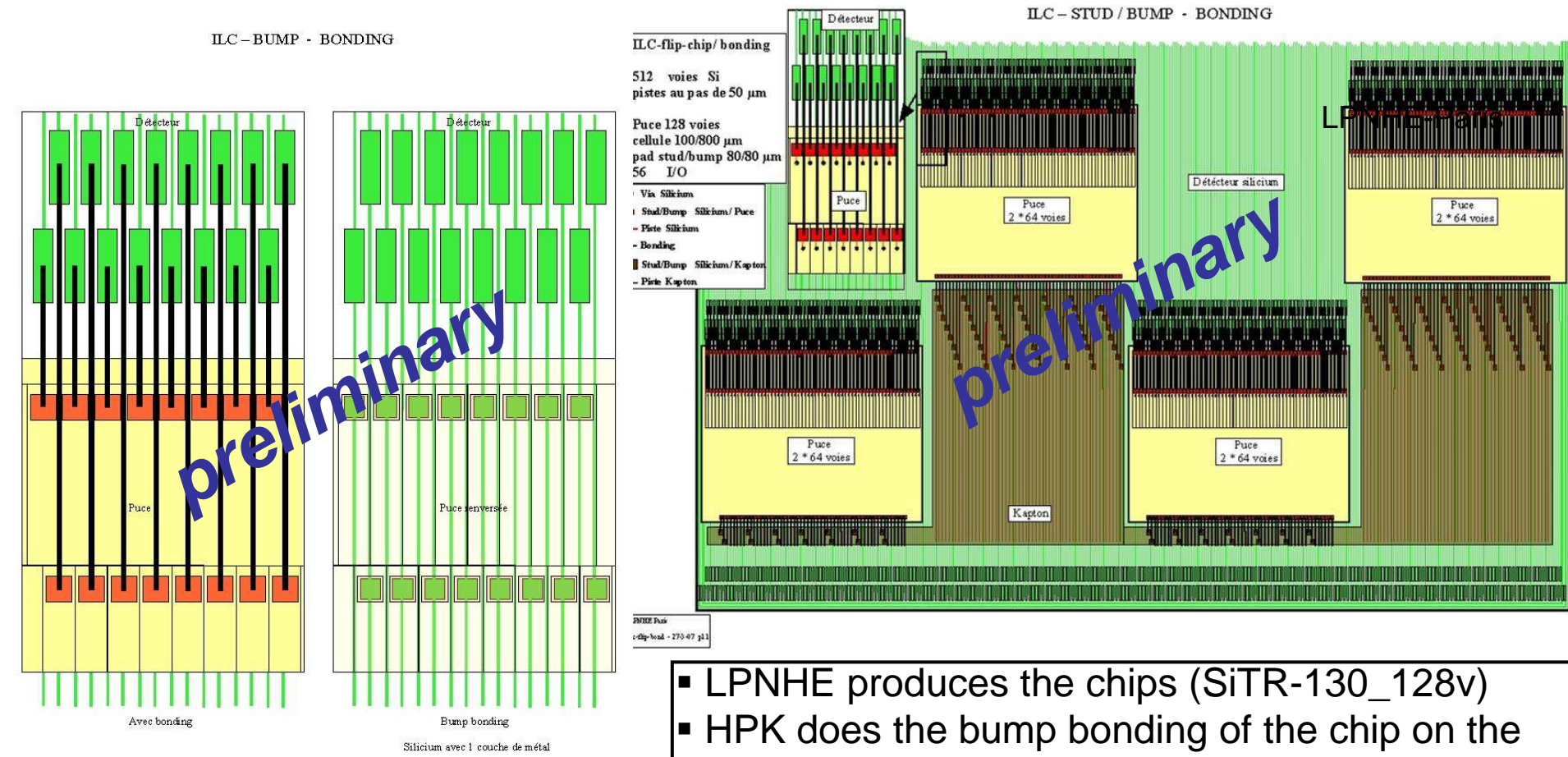


Tests of SiTR-130_v1 mounted on FE board connected to a Si module made of one CMS sensor (9,45cm strip long, 125 μ m pitch) made by IEKP, are underway at the Lab test bench in Paris before testbeam at CERN.

Tests with LD1060nm → The electronic chain works fine
Tests with radioactive source have just started
These tests are in preparation of CERN t.b. in October.

These tests are crucial for the new SiTR-130_128ch, based on same design, but with 128 ch/chip and power cycling; New chip will be sent in foundry January 8 (EUDET).

"Inline pitch adapter" of SiTR chip for SiLC



ILC-flip-chip/ bonding

512 voies Si
pistes au pas de 50 µm

Puce 128 voies
cellule 100/800 µm
pad Bump 60/60 µm
56 I/O

— Piste Silicium 10 µm
— Pad Bump 60 µm / 60 µm
— Pad Puce 80 µm / 80 µm
— Bonding 17µm

ILC-flip-chip/ bonding
512 voies Si
pistes au pas de 50 µm

Puce 128 voies
cellule 100/800 µm
pad stud/bump 80/80 µm
56 I/O

— Via Silicium
— Stud/Bump Silicium/ Puce
— Piste Silicium
— Bonding
— Stud/Bump Silicium/ Kapton
— Piste Kapton

ILC-flip-chip/ bonding
512 voies Si
pistes au pas de 50 µm

Puce 128 voies
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56 I/O

— Piste Silicium 10 µm
— Pad Bump 60 µm / 60 µm
— Pad Puce 80 µm / 80 µm
— Bonding 17µm

ILC-flip-chip/ bonding
512 voies Si
pistes au pas de 50 µm

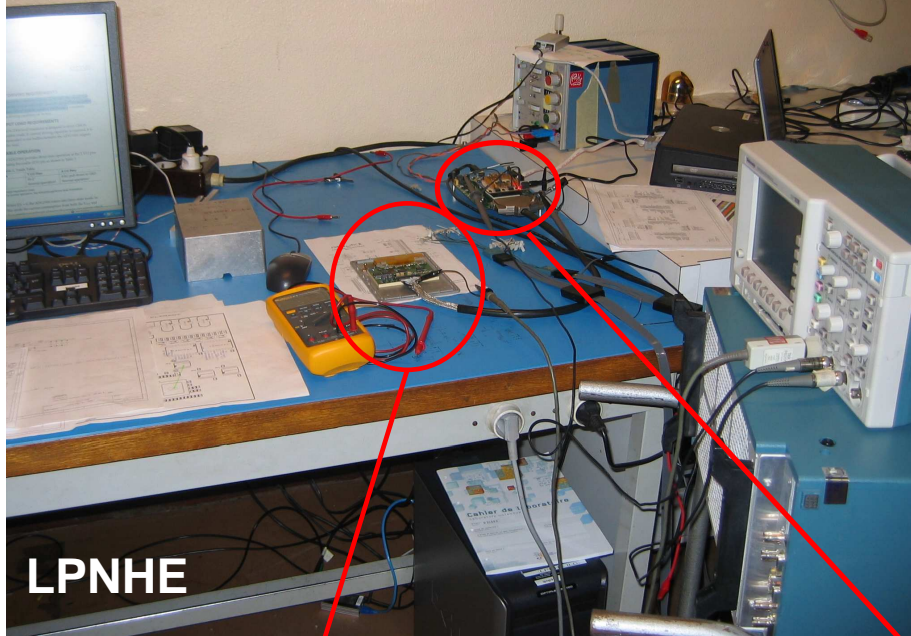
Puce 128 voies
cellule 100/800 µm
pad stud/bump 80/80 µm
56 I/O

— Via Silicium
— Stud/Bump Silicium/ Puce
— Piste Silicium
— Bonding
— Stud/Bump Silicium/ Kapton
— Piste Kapton

LPNHE + HPK

- LPNHE produces the chips (SiTR-130_128v)
- HPK does the bump bonding of the chip on the detector in:
 - Flipchip
 - Stud-bonding
 (MoU & NdA in preparation)
- Foreseen tests and mini production in 2008

New digitized FE-readout and new associated DAQ



LPNHE

LabView: 16ch x16samples

Face-avant de USB_Stand_Hung.vi

Channel 0

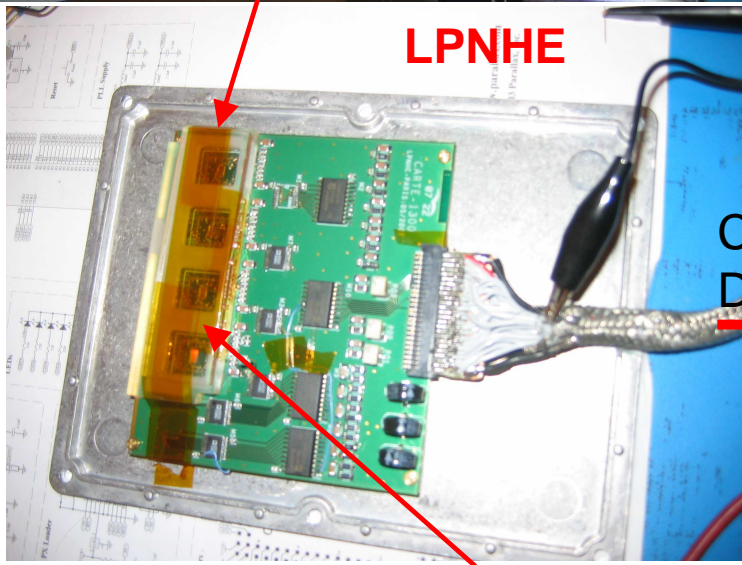
C050	EO	465E	5657	41	80AC	4A	5657	14B	21A3	40	4454	425E	C8C8	CCCC	4242
C0C0	0	4646	5656	0	8080	0	5656	101	2121	0	4444	4242	C8C8	CCCC	4242
C0C0	0	4646	5656	0	8080	0	5656	101	2121	0	4444	4242	C8C8	CCCC	4242
C0C0	0	4646	5656	0	8080	0	5656	101	2121	0	4444	4242	C8C8	CCCC	4242
23A3	C8C8	449C	5357	20F2	74F7	1896	5757	CECE	A2EA	424F	5595	242	EAEA	40	495C
2323	C8C8	4444	5353	2020	7474	1818	5757	CECE	A2A2	4242	5595	202	EAEA	0	4848
2323	C8C8	4444	5353	2020	7474	1818	5757	CECE	A2A2	4242	5595	202	EAEA	0	4848
2323	C8C8	4444	5353	2020	7474	1818	5757	CECE	A2A2	4242	5595	202	EAEA	0	4848
95B0	424F	5457	5057	E1	COCE	405C	4056	54F5	D0	1959	5457	8ADA	D4FD	494D	4054
9595	4242	5454	5050	0	C0C0	4848	4040	5454	0	1919	5454	8ABA	D4D4	4949	4040
9595	4242	5454	5050	0	C0C0	4848	4040	5454	0	1919	5454	8ABA	D4D4	4949	4040
9595	4242	5454	5050	0	C0C0	4848	4040	5454	0	1919	5454	8ABA	D4D4	4949	4040
80	48	4256	4056	8088	143	5455	4256	20E2	88CA	575F	5257	D8FD	40D6	48	5055
0	0	4242	4040	8080	101	5454	4242	2020	8888	5757	5252	D8D8	4040	0	5050
0	0	4242	4040	8080	101	5454	4242	2020	8888	5757	5252	D8D8	4040	0	5050

raw_data

0 3072 0 1134 1383 1 2060 10 1383 27 531 0 1092 1070 3212 3276 1070

Waveform of 16 samples

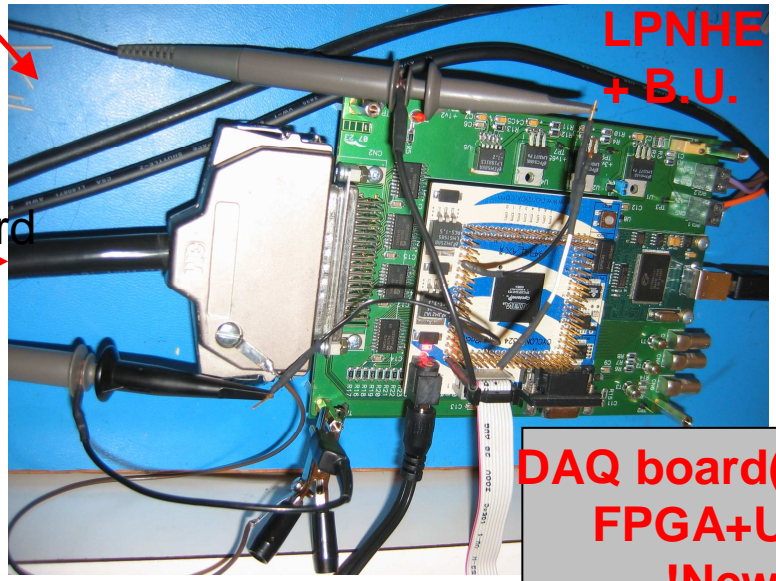
LPNHE



LPNHE

Cable to DAQ board

FE hybrid with 4 SiTR-130_v1
 → Total number of channels = 16

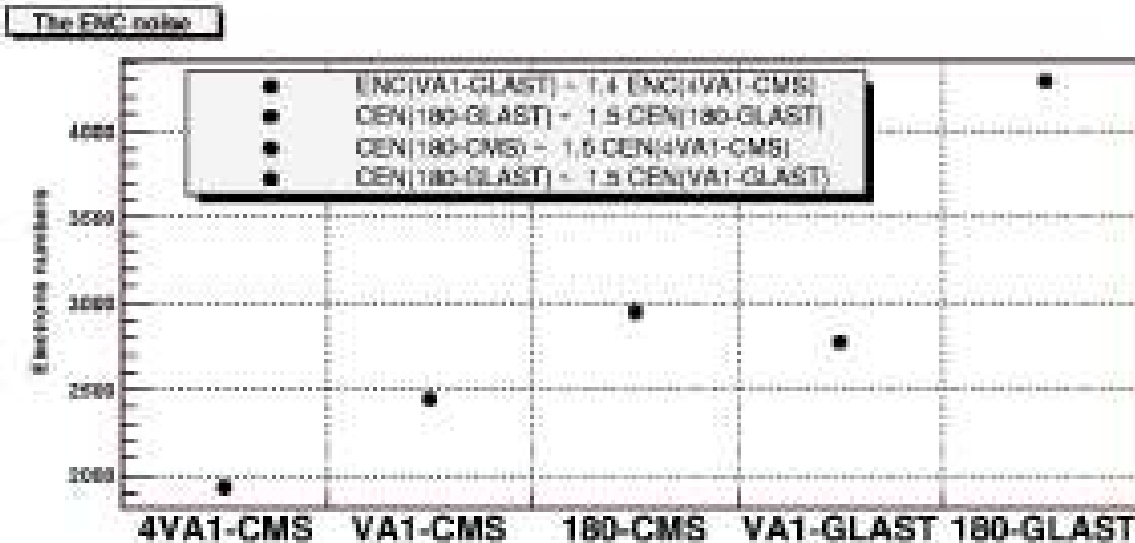
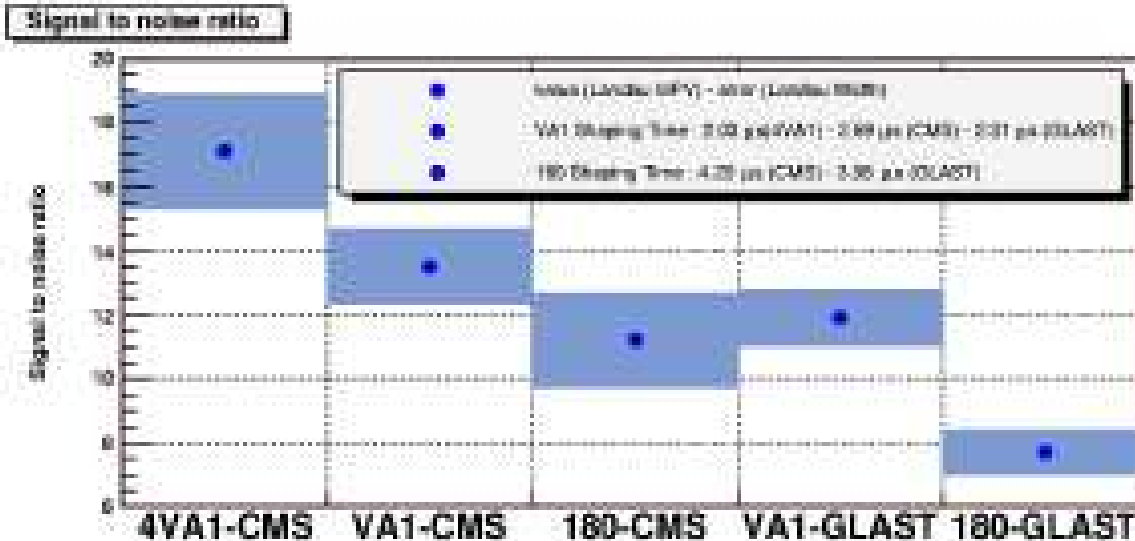


LPNHE + B.U.

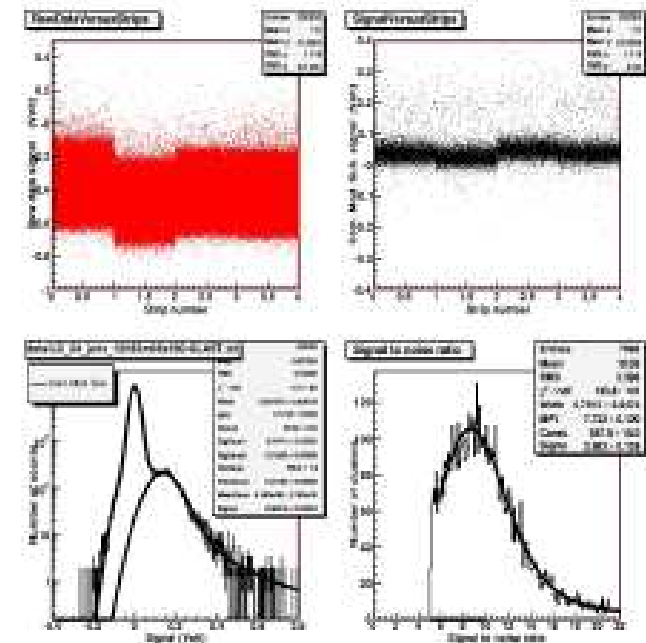
DAQ board(VHDL)
 FPGA+USB
 !New!

Characterization of Si detectors & FEE

Measurements S/N (MPV) and noise (ENC) at Lab test bench, on modules with 3CMS & 10 GLAST, read out by VA1 (ref) and SiTR-180



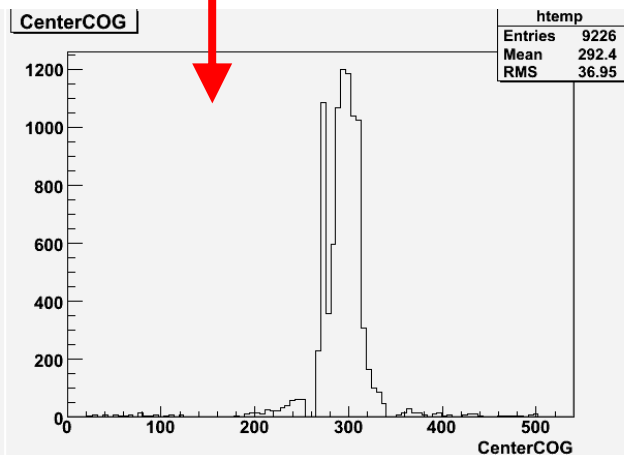
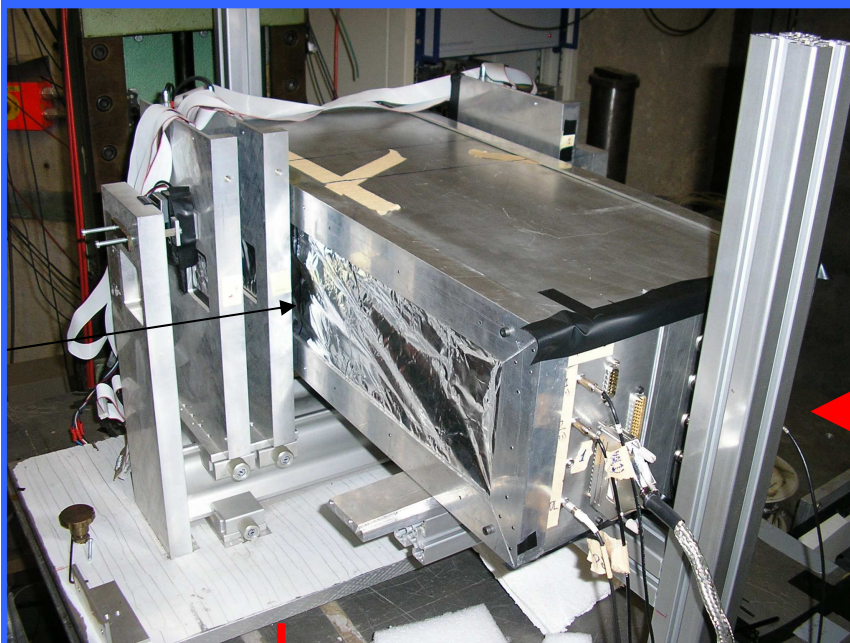
Signal Studies : 180-GLAST



S/N ~ 8

5°) Beam Tests (CU Prague, IFCA, IEKP, LPNHE & more joining)

- Tests at DESY 4/6 → 17/6, TB22, in preparation of:
- Tests at CERN 10/10 → 22/10, TB H6 at SPS
- Preparation of test with LCTPC: foreseen Fall 08.



DESY T.B:
BU, DESY, IEKP, LPNHE, Prague, IFCA
Coordinator SiTRA DESY T.B.: Z. Dolezal,
Contact person: V. Saveliev

→ Pursuing on tests at DESY (Nov06) & new Lab tests from testbench at LPNHE with CMS-180nm vs VA1 (ref)

→ Attempt to test S/N with Si module: 3CMS & 16ch of SiTR-130_v1prototype

- New DAQ Hardware: digitized FE+ FPGA + USB interface

- New DAQ software (VHDL + LabView)

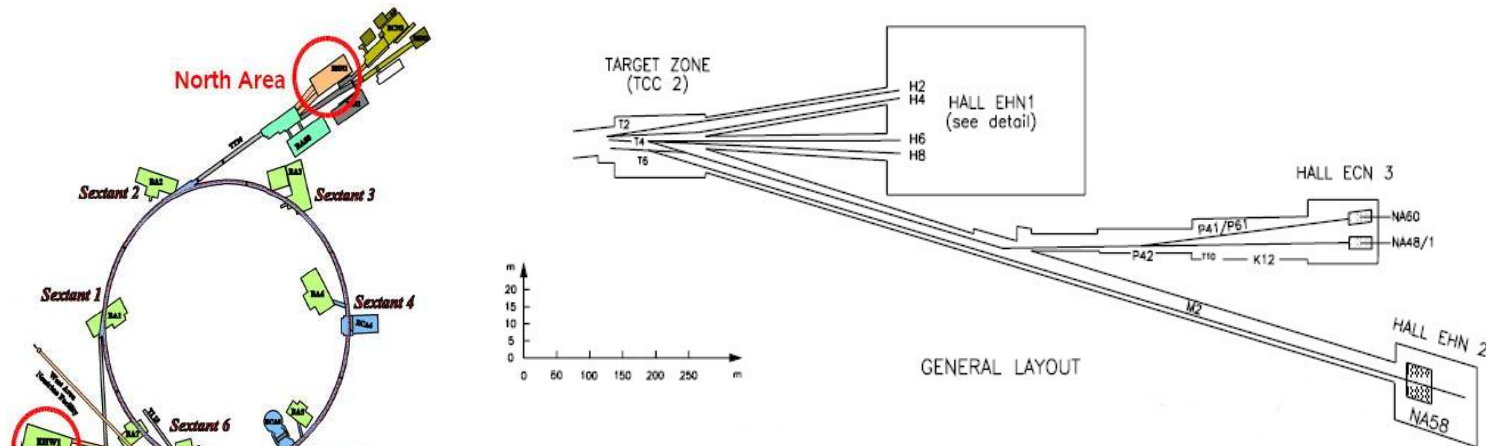
- New FE board

- New cabling

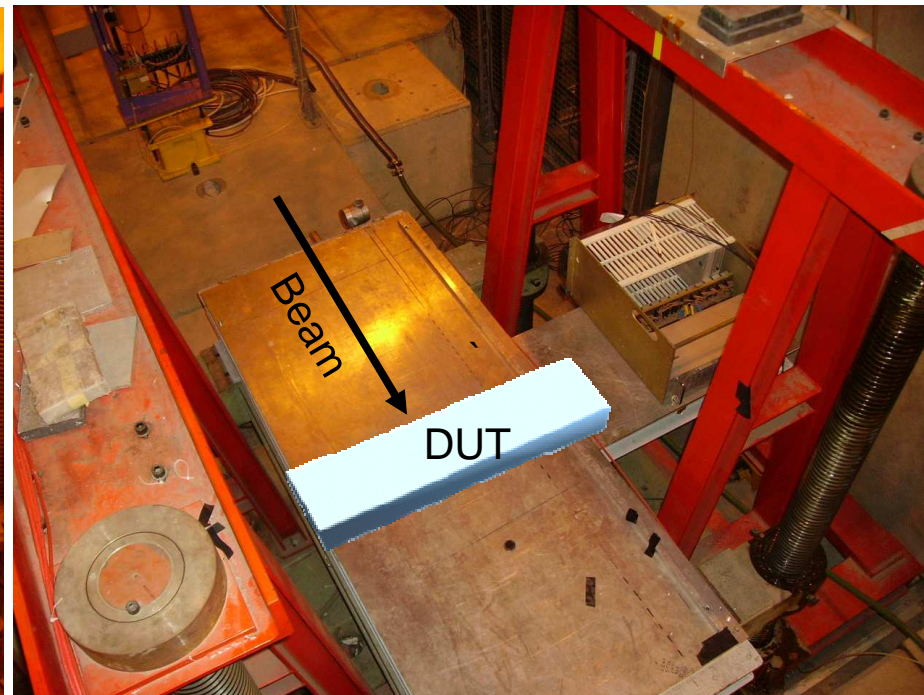
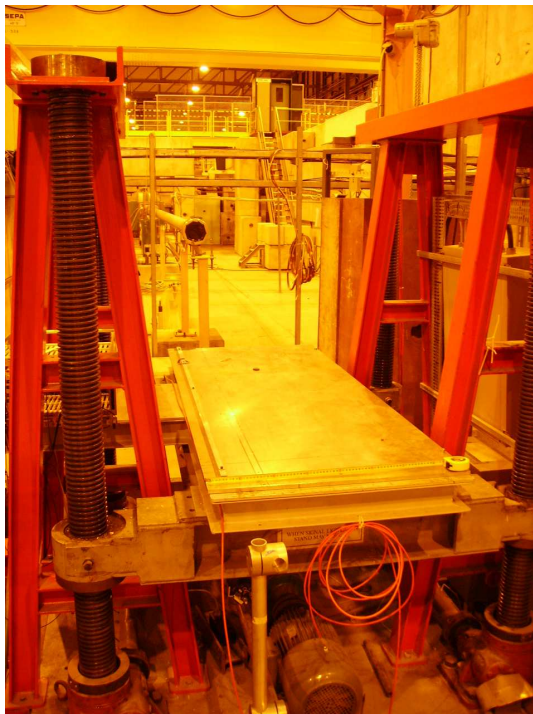
- Preliminary tests at the Paris Lab test bench DAQ hard + soft, new chip on FE board connected to Si module

Overall new 130nm-system could not be ready for June tests thus tests were pursued at Lab.

Contact person at CERN: Marcos Fernandez Garcia (IFCA & E.U. postdoc)
Coordinator SiTRA CERN T.B.: A. Savoy-Navarro



Test Beam at CERN: October 10-22, 2007

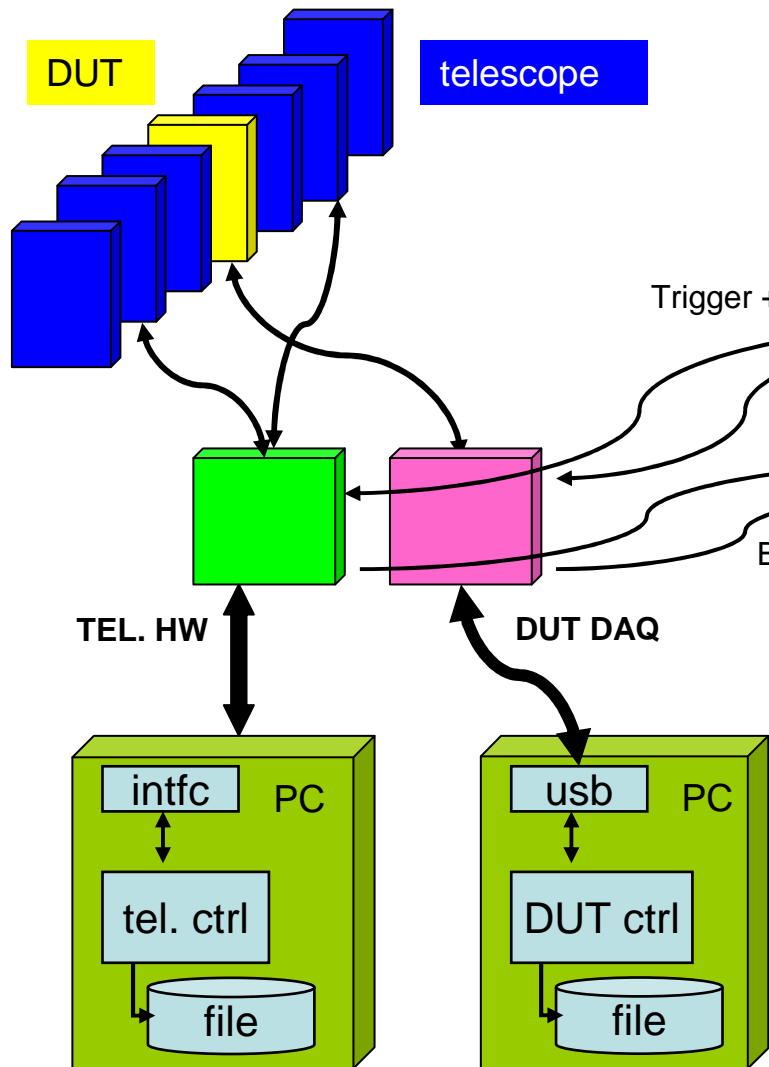


Objectives of CERN T.B.

- Two new modules made of 2 new Si HPK sensors that will be used for making large size prototypes (SiTRA deliverable) for next year test beams
- Compared with 2 modules read out with VA1
- (reference readout).
- New FE electronics prototype of the readout chip (SiTRA deliverable major funding component)
- New DUT DAQ and new overall Si-DAQ adapted to common EUDET-ILC DAQ
- First attempt of EUDET combined T.B., using vertex EUDET detectors (Tobias et al.) => see TA request

TELESCOPE + DUT TESTBEAM

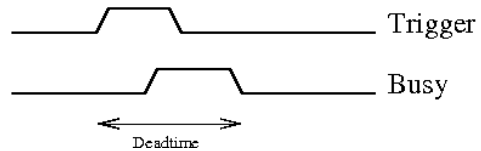
- Overall DAQ + Beam & trigger: IFCA + CU Prague
- Telescope DAQ: Telescope group
- DUT DAQ: LPNHE



Trigger Logic Unit (TLU) Beam Triggers



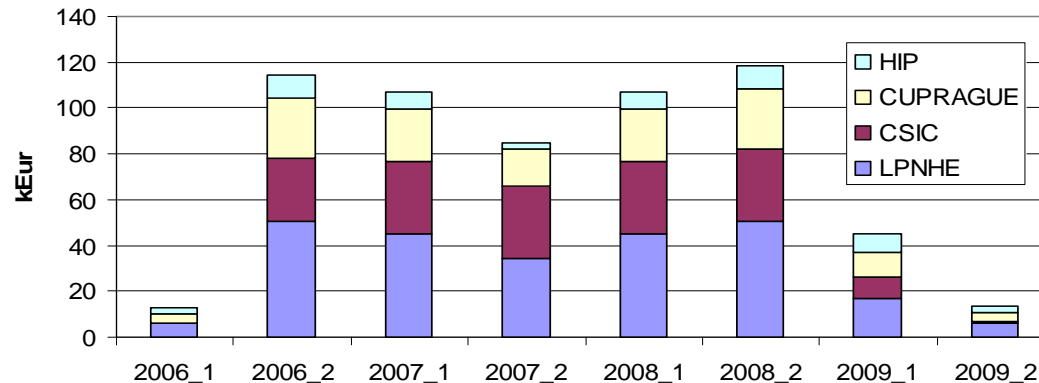
Simple Handshake



Trigger / Reset / Busy = LVDS, TTL

SiTRA: Appointments and Finances status

SITRA spending profile



+ 3 x 32 person months

Not clear all the 2 first years money will be spent end 2007: under evaluation

Appointment status: The 3 job positions are being filled

CU Prague: since August 2006 (Petr Kvasnicka)

IFCA Santander: since September 2006 (Marcos Fernandez Garcia)

LPNHE-Paris: First candidate, starts October 1st 2007

The 32 months are split into 2 positions. The 2nd candidate: end 07.

Total amount of money to be spent in 2007 under evaluation.

Largest part can be spent only for the FE chip foundry production but main foundry submission early January 2008. What about FE boards etc...All this is under evaluation.

Transnational Access: 2 weeks test beam in DESY+ travel support (CU Prague LPNHE)
Request for use of EUDET telescope prototype for T.B. at CERN in October



Critical points: (*not only for SiTRA*)

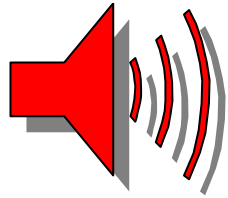


- **Financing**

Non E.U. funds are needed for: Silicon sensors, detector prototypes, part of cooling system, all the alignment system, DAQ and related electronics (FE boards etc...)

- **Collaboration with industry** on some of the high tech aspects is crucial (new sensors; wiring /packaging, VDMS foundries, new materials) and needs funding as well.

- **Test beam:** longer and far away (CERN & FNAL), thus increasing needs for travelling money



SiTRA positive points



- Important progress in 2007 on:
 - New large area Si tracking prototypes: IEKP, HEPHY, LPNHE and fruitful collaboration with CERN.
 - Front end chips
 - Alignment prototype & cooling prototype as well.
- Collaboration started with other sub detectors: TPC & μ vertex
- Valuable T.B. facility in DESY+ starting T.B. at CERN
- Non E.U. SiLC teams join beam tests (prepa & construction)
- Industrial firms starting active contributions on crucial aspects: new sensors & inline pitch adapter (new Si modules).
- Non E.U. financing increase for some teams (Spain, Vienna, France....); but not yet enough for the next years needs .
- R&D SiLC collaboration developing well: regular meetings of the whole collaboration or on dedicated topics + good visibility
=> valuable help for SiTRA

List of people contributing to SiTRA in 2007

SiTRA partners

- **HIP and VTT Helsinki:**

S. Eranen (VTT), R. Orava,
N. Van Remortel

- **LPNHE Paris:**

W. Dasilva, G. Daubard, J. David,
M. Dhellot, C. Evrard, J.F. Genat,
P. Ghislain, J.F. Huppert, D. Imbault,
F. Kapusta, H. Lebbolo, T.H. Pham,
Ph. Repain, F. Rossel, A. Savoy-N.,
R. Sefri + D. Fougeron, R. Hermel
(LAPP/IN2P3)

- **CU Prague**

Z. Dolezal, Z. Drasal, P. Kodys,
P. Kvasnicka (E.U. postdoc),
D. Scheirich

- **IFCA Santander**

M. Fernandez-Garcia(E.U. postdoc),
F.J.Gonzalez-Sanchez, R. Jaramillo,
C. Martinez-Rivero,A. Ruiz-Jimeno,
Ivan Vila

SITRA Associated

- **IMB-CNM Barcelona:**

E. Cabruja, M. Lozano, G. Pellegrini, L.Teres

- **IEKP Karlsruhe:** P. Bluem, M. Frey,
F. Hartmann, P. Lederman, T. Muller

- **Liverpool Uni.:** Ph. Allport, T. Greenshaw

- **OSU, Obninsk:** V. Saveliev

- **IFIC Valencia:** A. Faus-Golfe, J. Fuster,
C. Lacasta, P. Modesto, M. Vos

- **HEPHY Vienna:** T. Bergauer,
M. Krammer, W. Mitaroff, M. Regler

Collaboration of CERN bonding Lab

A. Honma, I. McGill, M.Moll

DESY: test beam+ telescope

N. Meyers, T. Hass & al.

HPK Hamamatsu

and SiLC R&D collaboration